

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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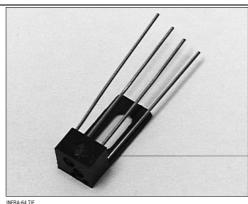




### **Reflective Sensor**

#### **FEATURES**

- Choice of phototransistor or photodarlington output
- Focused for maximum response
- Wide operating temperature range (- 55°C to +100°C)



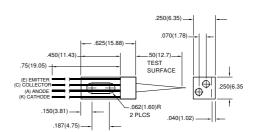
#### DESCRIPTION

The HOA2498 series consists of an infrared emitting diode and an NPN silicon phototransistor (HOA2498-001, - 002) or photodarlington (HOA2498-003), encased side-by-side on converging optical axes in a black thermoplastic housing. The detector responds to radiation from the IRED only when a reflective object passes within its field of view. The HOA2498 series employs metal can packaged components. For additional component information see SE1450, SD1440, and SD1410.

Housing material is polyester. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

### OUTLINE DIMENSIONS in inches (mm)

3 plc decimals ±0.010(0.25) 2 plc decimals ±0.020(0.51)



DIM\_039.ds4



### **Reflective Sensor**

#### ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER  | SYMBOL                          | MIN                 | TYP      | MAX               | UNITS | TEST CONDITIONS   |
|--|---------------------------------|---------------------|----------|-------------------|-------|---|
| IR EMITTER   |                                 |                     |          |                   |       |   |
| Forward Voltage  | VF                              |                     |          | 1.6               | V     | I <sub>F</sub> =20 mA   |
| Reverse Leakage Current  | I <sub>R</sub>                  |                     |          | 10                | μΑ    | V <sub>R</sub> =3 V   |
| DETECTOR Collector-Emitter Breakdown Voltage HOA2498-001, -002 HOA2498-003             | V <sub>(BR)</sub> ceo           | 30<br>15            |          |                   | V     | Ic=100 μA   |
| Emitter-Collector Breakdown Voltage  | V <sub>(BR)ECO</sub>            | 5.0                 |          |                   | V     | I <sub>E</sub> =100 μA  |
| Collector Dark Current<br>HOA2498-001, -002<br>HOA2498-003                             | Iceo                            |                     |          | 100<br>250        | nA    | V <sub>CE</sub> =10 V<br>I <sub>F</sub> =0  |
| COUPLED CHARACTERISTICS On-State Collector Current HOA2498-001 HOA2498-002 HOA2498-003 | Ic(on)                          | 0.04<br>0.16<br>2.0 |          |                   | mA    | VcE=5 V<br>IF=30 mA<br>(1)  |
| Collector-Emitter Saturation Voltage<br>HOA2498-001<br>HOA2498-002<br>HOA2498-003      | VCE(SAT)                        |                     |          | 0 4<br>0 4<br>1 1 | V     | I <sub>F</sub> =30 mA <sup>(1)</sup><br>I <sub>C</sub> =5 μΑ<br>I <sub>C</sub> =20 μΑ<br>I <sub>C</sub> =250 μΑ |
| Rise And Fall Time<br>HOA2498-001, -002<br>HOA2498-003                                 | t <sub>r</sub> , t <sub>f</sub> |                     | 15<br>75 |                   | μs    | $V_{CC}$ =5 V, I <sub>C</sub> =1 mA R <sub>L</sub> =1000 $\Omega$ R <sub>L</sub> =100 $\Omega$                  |

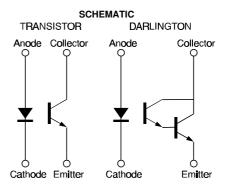
#### **ABSOLUTE MAXIMUM RATINGS**

(25°C Free-Air Temperature unless otherwise noted) Operating Temperature Range -55°C to 100°C Storage Temperature Range -55°C to 125°C Soldering Temperature (10 sec) 260°C

IR EMITTER

Power Dissipation 75 mW (1) Reverse Voltage 3 V 50 mA Continuous Forward Current

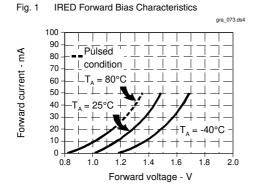
**DETECTOR** TRANS. **DARLINGTON** 30 V 15 V Collector-Emitter Voltage **Emitter-Collector Voltage** 5 V 5 V 75 mW <sup>(1)</sup> 75 mW (1) Power Dissipation Collector DC Current 30 mA 30 mA



Honeywell reserves the right to make changes in order to improve design and supply the best products possible. Honeywell

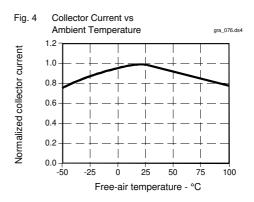
Notes
1. Test surface is a front surface mirror (polished aluminum, 85% reflectance) located 0.50 in.(12.7 mm) from the front surface of the

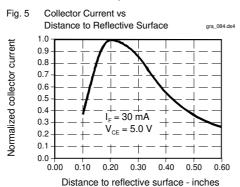
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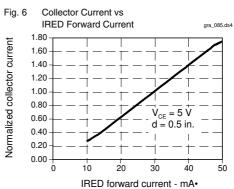


Non-Saturated Switching Time vs Load Resistance gra\_079.ds4 1000 ≡ı≡⊞ Response time - µs 100 Photodarlington = | | Phototransistor ŦI#I# 10 100 1000 10000 Load resistance - Ohms

Dark Current vs Fig. 3 Temperature gra\_303.cdr 100000 10000 VCE = 15 V 1000 H = 0100 Dark current - nA 0.1 0.01 0.001 20 40 60 80 100 120 140 Free-air temperature - °C







All Performance Curves Show Typical Values

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